

## **IXFH30N85X Datasheet**



https://www.DiGi-Electronics.com

DiGi Electronics Part Number IXFH30N85X-DG

Manufacturer IXYS

Manufacturer Product Number IXFH30N85X

Description MOSFET N-CH 850V 30A TO247AD

Detailed Description N-Channel 850 V 30A (Tc) 695W (Tc) Through Hole

TO-247 (IXTH)



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



## **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
IXFH30N85X	IXYS
Series:	Product Status:
HiPerFET™, Ultra X	Active
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
850 V	30A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ Id, Vgs:
10V	220mOhm @ 500mA, 10V
Vgs(th) (Max) @ Id:	Gate Charge (Qg) (Max) @ Vgs:
5.5V @ 2.5mA	68 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±30V	2460 pF @ 25 V
FET Feature:	Power Dissipation (Max):
	695W (Tc)
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Through Hole
Supplier Device Package:	Package / Case:
TO-247 (IXTH)	TO-247-3
Base Product Number:	
IXFH30	

## **Environmental & Export classification**

8541.29.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



## **OUR CERTIFICATE**

DiGi provide top-quality products and perfect service for customer worldwide through standardization, technological innovation and continuous improvement. DiGi through third-party certification, we striciy control the quality of products and services. Welcome your RFQ to Email: Info@DiGi-Electronics.com

















Tel: +00 852-30501935